



**OptoSupply**

*Light It Up*

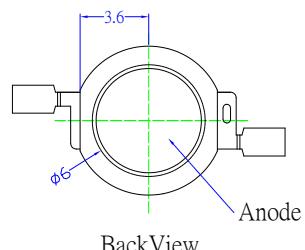
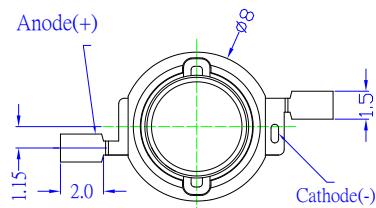
**0.84W 850nm Infrared Emitter LED**

**OSI3XNE1C1E**

## ■Features

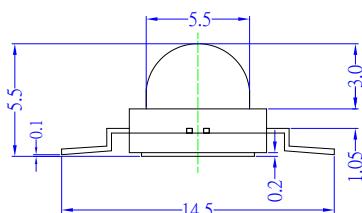
- High Radiant Power
- Super Energy Efficiency
- Long Lifetime Operation
- Superior UV Resistance

## ■Outline Dimension



Anode ————— Cathode

Unit:mm  
Tolerance: $\pm 0.20\text{mm}$   
unless otherwise noted



## ■Applications

- Night Vision
- Camera
- Outdoor/Indoor applications

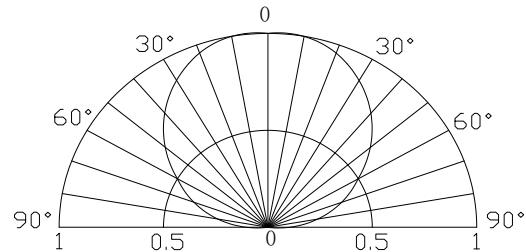
(Ta=25°C)

## ■Absolute Maximum Rating

Item	Symbol	Value	Unit
DC Forward Current	I <sub>F</sub>	400	mA
Pulse Forward Current#	I <sub>FP</sub>	1750	mA
Reverse Voltage	V <sub>R</sub>	5	V
Power Dissipation	P <sub>D</sub>	0.84	mW
Operating Temperature	T <sub>opr</sub>	-30 ~ +85	°C
Storage Temperature	T <sub>tsg</sub>	-40 ~ +100	°C
Lead Soldering Temperature	T <sub>sol</sub>	260°C/5sec	-

#Pulse width Max.10ms Duty ratio max 1/10

## ■Directivity



## ■Electrical –Optical Characteristics

(Ta=25°C)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
DC Forward Voltage*1	V <sub>F</sub>	I <sub>F</sub> =350mA	-	1.8	2.1	V
DC Reverse Current	I <sub>R</sub>	V <sub>R</sub> =5V	-	-	10	μA
Peak Wavelength*2	λ <sub>p</sub>	I <sub>F</sub> =350mA	-	850	-	nm
Radiant Power*3	P <sub>O</sub>	I <sub>F</sub> =350mA	165	180	-	mW
Radiant Intensity*4	E <sub>e</sub>	I <sub>F</sub> =350mA	165	180	-	mW/Sr
50% Power Angle	2θ <sub>1/2</sub>	I <sub>F</sub> =350mA	-	120	-	deg

\*1 Tolerance of measurements of forward voltage is  $\pm 0.1\text{V}$

\*2 Tolerance of measurements of peak wavelength is  $\pm 1\text{nm}$

\*3 Tolerance of measurements of Radiant Power is  $\pm 15\%$

\*4 Tolerance of measurements of radiant intensity is  $\pm 15\%$

Note: Don't drive at rated current more than 5s without heat sink for Xeon 0.6 emitter series.

**LED & Application Technologies**

